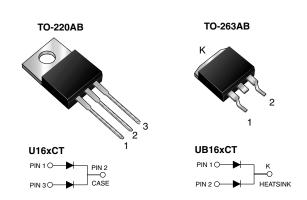


New Product U(B)16BCT thru U(B)16DCT

Vishay General Semiconductor

Dual Common-Cathode Ultrafast Plastic Rectifier



8 A x 2

100 V, 150 V, 200 V

80 A

35 ns

0.87 V

150 °C

PRIMARY CHARACTERISTICS

I_{F(AV)} V_{RRM}

I_{FSM}

t_{rr}

 V_F at $I_F = 8 A$

T_{.1} max.

FEATURES

- Oxide planar chip junction
- Ultrafast recovery time
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection specifically for DCM application.

MECHANICAL DATA

Case: TO-220AB and TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		U(B)16BCT	U(B)16CCT	U(B)16DCT	UNIT		
Maximum repetitive peak reverse voltage		100	150	200	V		
Max. average forward rectified current (Fig. 1) total device per diode	I _{F(AV)}	16 8		А			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	80		А			
Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 k Ω (contact mode)	V _C	8		kV			
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C		

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ROHS COMPLIANT

U(B)16BCT thru U(B)16DCT

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ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode $^{(1)}$	I _F = 4 A I _F = 8 A	T _J = 25 °C	V _F	0.90 0.99	- 1.10	v	
	I _F = 4 A I _F = 8 A	T _J = 125 °C		0.77 0.87	- 0.95		
Reverse current per diode (2)	rated V _R	T _J = 25 °C T _J = 125 °C	I _R	0.5 155	10 600	μΑ	
Reverse recovery time per diode	$I_{\rm F} = 0.5 {\rm A}, I_{\rm R} = 1.0 {\rm A}, I_{\rm rr} = 0.25 {\rm A}$		t _{rr}	28	35	ns	
Reverse recovery time per diode	I _F = 8 A, dI/dt = 20 A/μs, V _R = 200 V, I _{rr} = 0.1 I _{RM}		t _{rr}	67	80	ns	
Stored charge per diode			Q _{rr}	33	-	nC	
Forward recovery time per diode	$I_F = 8 \text{ A}, \text{ dl/dt} = 64 \text{ A/}\mu\text{s},$ $V_F = 1.1 \text{ x } V_F \text{ max}.$		t _{fr}	160	-	ns	
Peak forward voltage per diode			V _{FP}	3.3	-	V	

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL U16xCT UB16xCT		UB16xCT	UNIT		
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	3.5		°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	U16DCT-E3/4W	1.87	4W	50/tube	Tube	
TO-263AB	UB16DCT-E3/4W	1.31	4W	50/tube	Tube	
TO-263AB	UB16DCT-E3/8W	1.31	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

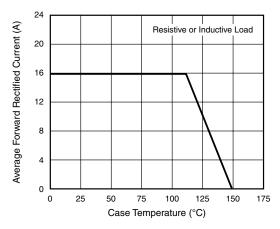


Figure 1. Maximum Forward Current Derating Curve

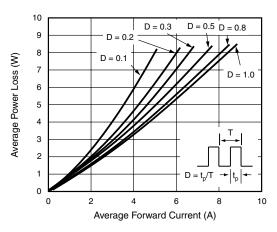


Figure 2. Forward Power Loss Characteristics Per Diode

For technical questions within your region, please contact one of the following: <u>PDD-Americas@vishay.com</u>, <u>PDD-Asia@vishay.com</u>, <u>PDD-Europe@vishay.com</u>



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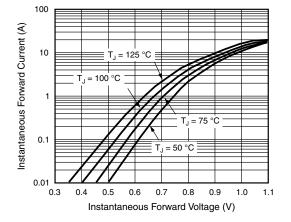


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

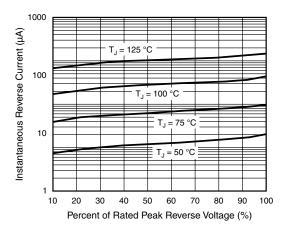


Figure 4. Typical Reverse Characteristics Per Diode

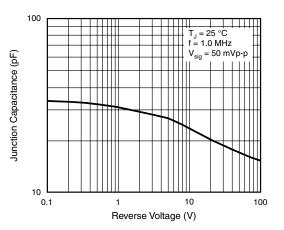


Figure 5. Typical Junction Capacitance Per Diode

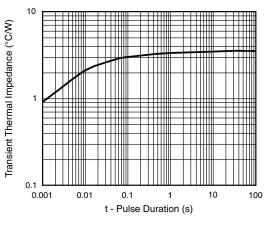
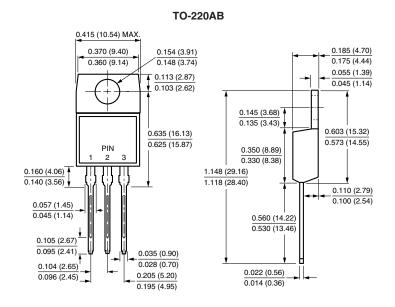


Figure 6. Typical Junction Capacitance Per Diode

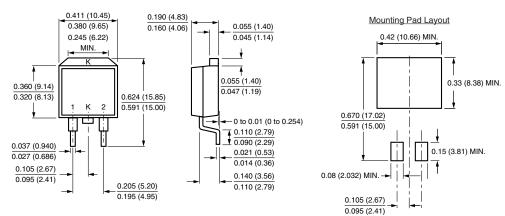
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TO-263AB



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